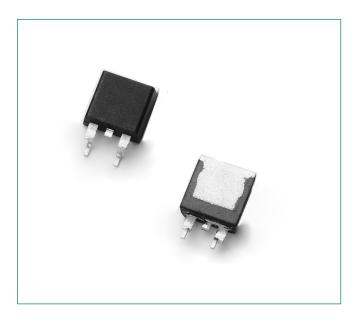


MCR12DCM, MCR12DCN





Features

Description

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- UL Recognized compound meets flammability rating V-0.

This thyristor is designed primarily for half-wave ac control applications, such as motor controls, heating controls, and power supplies; or wherever half-wave, silicon gate-

- ESD Ratings: Human Body Model, 3B > 8000 V
 Machine Model, C > 400 V
- Pb-Free Packages are Available

controlled devices are needed.

Pin Out



Functional Diagram



Additional Information





Samples

Τ,

 $\mathsf{T}_{\mathrm{stg}}$

-40 to 150

°C



Maximum Ratings $(T_1 = 25^{\circ}C \text{ unless otherwise noted})$ Rating **Symbol** Value Unit MCR12DCM $\mathrm{V}_{_{\mathrm{DRM}}}$ 600 Peak Repetitive Off-State Voltage (Note 1) (- 40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) MCR12DCN V_{RRM} 800 On-State RMS Current 12 Α I_{T (RMS)} (180° Conduction Angles; T_c = 90°C) Average On-State Current Α 7.8 I_{T(AV)} (180° Conduction Angles; T_C = 90°C) Peak Non-Repetitive Surge Current I_{TSM} 100 Α (1/2 Cycle, Sine Wave 60 Hz, T, = 125°C) Circuit Fusing Consideration (t = 8.3 ms) l2t 41 A²sec Forward Peak Gate Power P_{GM} 5.0 W (Pulse Width \leq 10 µsec,T $_{\rm C}$ = 90°C) Forward Average Gate Power P_{GM (AV)} 0.5 W $(t = 8.3 \text{ msec}, T_c = 90^{\circ}\text{C})$ Forward Peak Gate Current 2.0 Α (Pulse Width \leq 1.0 µsec, $T_{\rm C}$ = 90°C) °C -40 to 125

Thermal Characteristics

Storage Temperature Range

Operating Junction Temperature Range

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	Re _{JC}	2.2	
Thermal Resistance, Junction-to-Ambient	R _{θ_{JA}}	88	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	ReJA	80	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T _L	260	°C

Electrical Characteristics - **OFF** $(T_J = 25^{\circ}C)$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current ($V_{AK} = Rated V_{DRM}$	T _J = 25°C	I _{DRM}	-	-	0.01	m ^
or V _{RRM} Gate Open)	T _J = 125°C	IRRM	-	-	5.0	mA mA

Electrical Characteristics - ON (T, = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Forward On-State Voltage (Note 2) (I _{TM} = 16 A)		V _{TM}	-	1.3	1.9	V
Gate Trigger Current (Continuous dc)	e Trigger Current (Continuous dc)		2.0	7.0	20	A
$(V_D = 12 \text{ V}; R_L = 100 \Omega)$	T _J = -40°C	40°C I _{GT} _	_	_	40	mA
Gate Trigger Voltage (Continuous dc)	ite Trigger Voltage (Continuous dc)		0.5	0.65	1.0	V
T _J = 12 V, R _L = 100 Ω) $T_{J} = -40^{\circ}C$		_	_	2.5	V	
Gate Non-Trigger Voltage ($V_D = 12 \text{ V}, R_L = 100 \Omega$)	$T_J = 125^{\circ}C$	V _{GD}	0.2	_	_	V
Holding Current	T _J = 25°C	I _H	4.0	22	40	mA
$(V_D = 12 \text{ V}, \text{ Gate Open, Initiating Current} = 200 \text{ mA})$	T _J = -40°C		_	_	80	
Latch Current $(V_D = 12 \text{ V, } I_C = 20 \mu\text{A}, T_1 = 25^{\circ}\text{C})$			4.0	22	40	mA
$(V_D - 12 \text{ V, } I_G - 20 \mu\text{A, } I_J - 23 \text{ C})$ $(V_D = 12 \text{ V, } I_G = 40 \mu\text{A, } T_J = -40 \text{ °C})$		'L	-	_	80	

Maximum ratings are those values beyond which component damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, component functional operation is not implied, damage may occur and reliability may be affected.

V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



Dynamic Characteristics Characteristic **Symbol** Min Тур Max Unit Critical Rate of Rise of Off-State Voltage dv/dt 50 200 V/µs $(V_D = Rated V_{DRM} Exponential Waveform, Gate Open, T_i = 125°C)$

- 2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.
- 3. 1/8* from case for 10 seconds.
 4. Pulse Test: Pulse Width ≤ 2.0 msec, Duty Cycle ≤ 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current

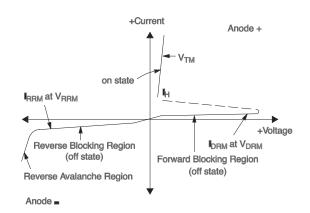


Figure 1. Average RMS Current Derating

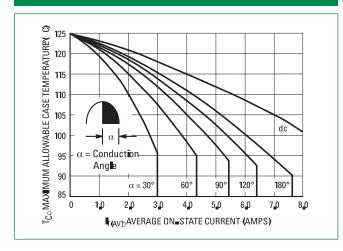


Figure 2. On-State Power Dissipation

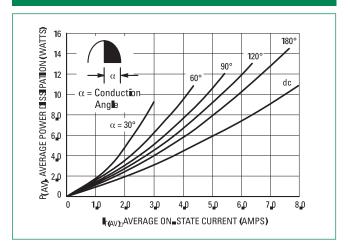




Figure 3. On-State Characteristics

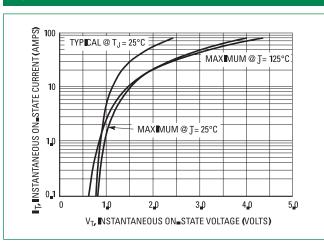


Figure 4. Transient Thermal Response

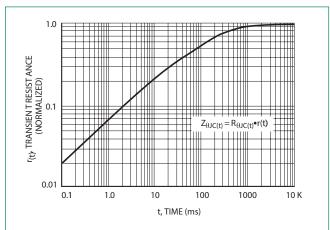


Figure 5. Typical Gate Trigger Current vs Junction Temperature

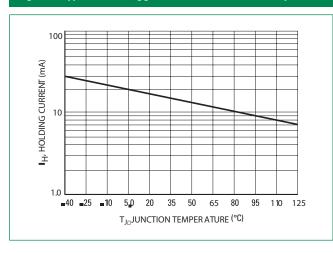


Figure 6. Typical Gate Trigger Voltage vs Junction Temperature

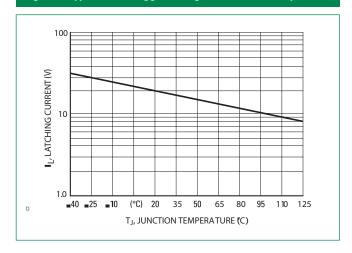


Figure 7. Typical Holding Current vs Junction Temperature

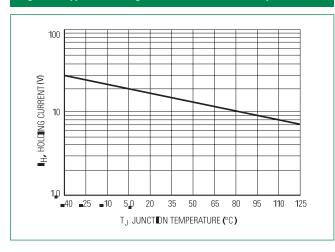
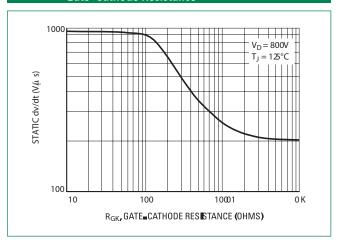
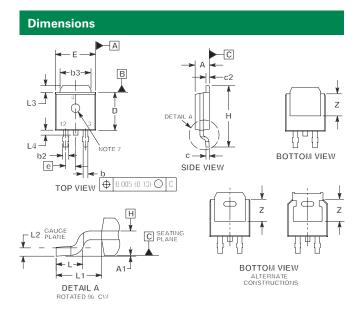


Figure 9. Exponential Static dv/dt vs Gate-Cathode Resistance





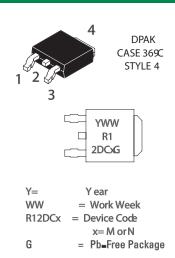


Millimeters Inches Dim Min Max Min Max Α 0.087 0.094 2.20 2.40 Α1 0.000 0.005 0.00 0.12 0.030 0.55 0.022 0.75 b b2 0.026 0.033 0.65 0.85 b3 0.209 0.217 5.30 5 50 0.019 С 0.023 0.49 0.59 c2 0.019 0.023 0.49 0.59 D 0.213 0.224 5.40 5.70 Ε 0.252 0.260 6.40 6.60 0.091 2.30 е Н 0.374 0.406 9.50 10.30 0.058 0.070 1.47 1.78 L1 0.114 L2 0.019 0.023 0.49 0.59 L3 0.053 0.065 1.35 1.65 L4 0.028 0.039 0.70 1.00 Ζ 0.154 3.90

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

Part Marking System



Pin Assignment				
1	Cathode			
2	Anode			
3	Gate			
4	Anode			

Ordering Information

Device	Package	Shipping
MCR12DCMT4	DPAK	
MCR12DCMT4G	DPAK (Pb-Free)	2500 /
MCR12DCNT4	TO-220AB	Tape & Reel
MCR12DCNT4G	DPAK (Pb-Free)	

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